MOSFETs Silicon N-Channel MOS (DTMOSIV)

# **TK17N65W**

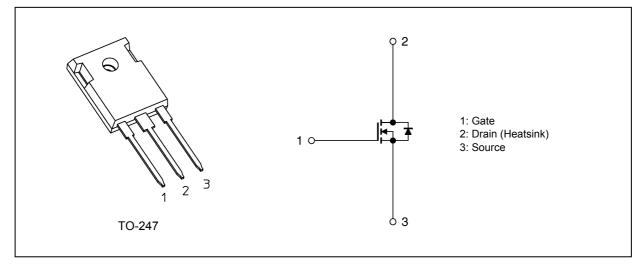
## 1. Applications

Switching Voltage Regulators

### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.17 \Omega$  (typ.) by used to Super Junction Structure : DTMOS
- (2) Easy to control Gate switching
- (3) Enhancement mode:  $V_{th}$  = 2.5 to 3.5 V ( $V_{DS}$  = 10 V,  $I_D$  = 0.9 mA)

## 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

Characteristics			Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	650	V
Gate-source voltage		V <sub>GSS</sub>	±30	
Drain current (DC)	(Note 1)	I <sub>D</sub>	17.3	A
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	69.2	
Power dissipation (T <sub>c</sub> =	25°C)	PD	165	W
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	210	mJ
Avalanche current		I <sub>AR</sub>	4.4	A
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	17.3	7
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	69.2	
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	7
Mounting torque		TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production

### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	0.757	°C/W
Channel-to-ambient thermal resistance	R <sub>th(ch-a)</sub>	83.3	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V\_DD = 90 V, T\_ch = 25°C (initial), L = 19.2 mH, R\_G = 25  $\Omega$ , I\_{AR} = 4.4 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

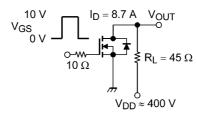
### 6. Electrical Characteristics

### 6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±30 V, $V_{DS}$ = 0 V	_	_	±1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 650 V, V <sub>GS</sub> = 0 V	_	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	650	_	—	V
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.9 mA	2.5	—	3.5	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 8.7 A		0.17	0.2	Ω

## 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 300 V, V <sub>GS</sub> = 0 V, f = 1 MHz		1800	_	pF
Reverse transfer capacitance	C <sub>rss</sub>			7	_	
Output capacitance	C <sub>oss</sub>	]		40	_	
Effective output capacitance	C <sub>o(er)</sub>	$V_{DS}$ = 0 to 400 V, $V_{GS}$ = 0 V		65	_	
Gate resistance	r <sub>g</sub>	V <sub>DS</sub> = OPEN, f = 1 MHz		1.5	_	Ω
Switching time (rise time)	tr	See Figure 6.2.1		15	_	ns
Switching time (turn-on time)	t <sub>on</sub>	]		50	_	
Switching time (fall time)	t <sub>f</sub>	]		6	_	
Switching time (turn-off time)	t <sub>off</sub>	]		100		
MOSFET dv/dt ruggedness	dv/dt	V <sub>DD</sub> = 0 to 400 V, I <sub>D</sub> = 8.7 A	50	_	_	V/ns



Duty  $\leq$  1 %, t<sub>w</sub> = 10  $\mu$ s

#### Fig. 6.2.1 Switching Time Test Circuit

## 6.3. Gate Charge Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 400 \text{ V},  V_{GS} \text{ = } 10  \text{V},  \text{I}_{D} \text{ = } 17.3  \text{A}$	_	45	—	nC
Gate-source charge 1	Q <sub>gs1</sub>			11	_	
Gate-drain charge	Q <sub>gd</sub>		_	20	_	

## 6.4. Source-Drain Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V <sub>DSF</sub>	I <sub>DR</sub> = 17.3 A, V <sub>GS</sub> = 0 V	_	_	-1.7	V
Reverse recovery time		I <sub>DR</sub> = 8.7 A, V <sub>GS</sub> = 0 V	_	300	_	ns
Reverse recovery charge	Q <sub>rr</sub>	-dI <sub>DR</sub> /dt = 50 A/μs	_	2.7	_	μC
Peak reverse recovery current	l <sub>rr</sub>			16		А
Diode dv/dt ruggedness	dv/dt	$I_{DR}$ = 8.7 A, $V_{GS}$ = 0 V, $V_{DD}$ = 400 V	15	_	_	V/ns

## 7. Marking (Note)

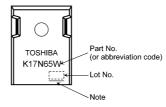
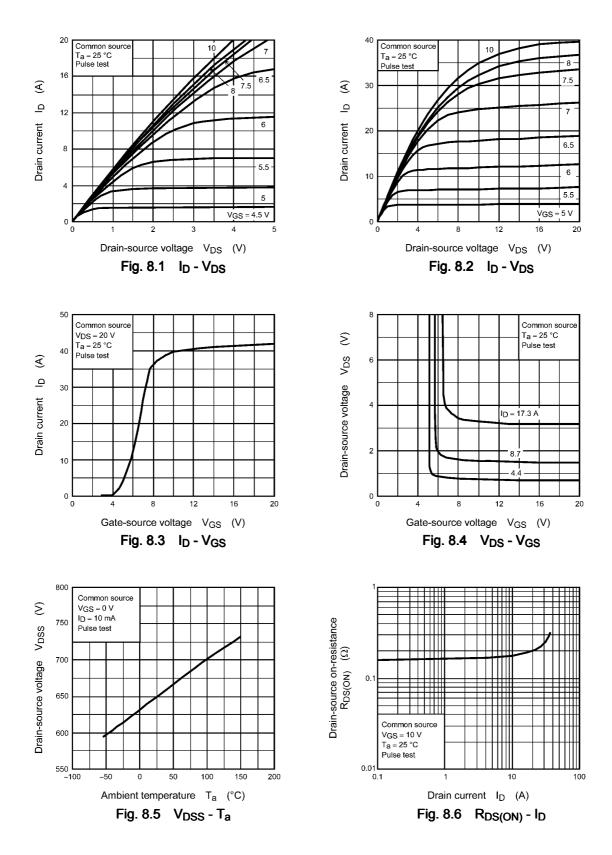
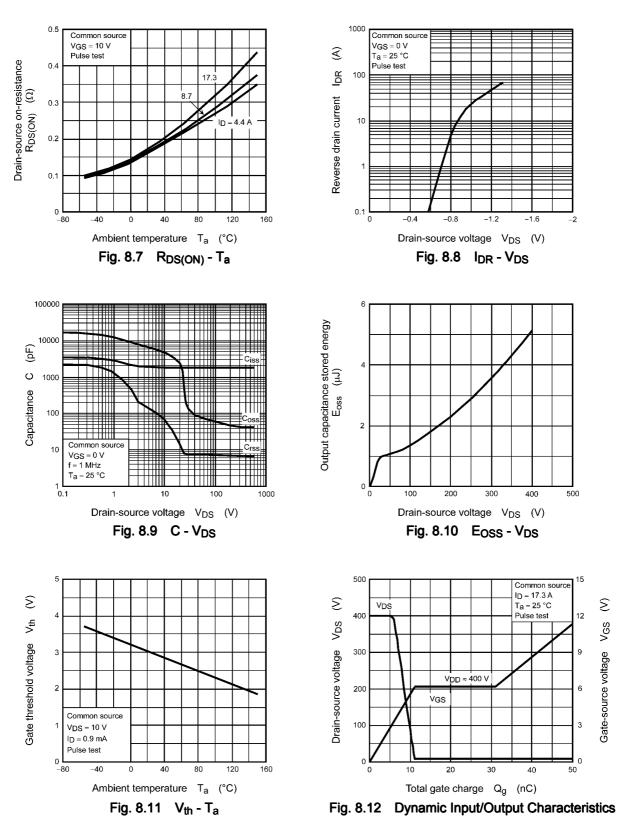


Fig. 7.1 Marking

 Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

## 8. Characteristics Curves (Note)







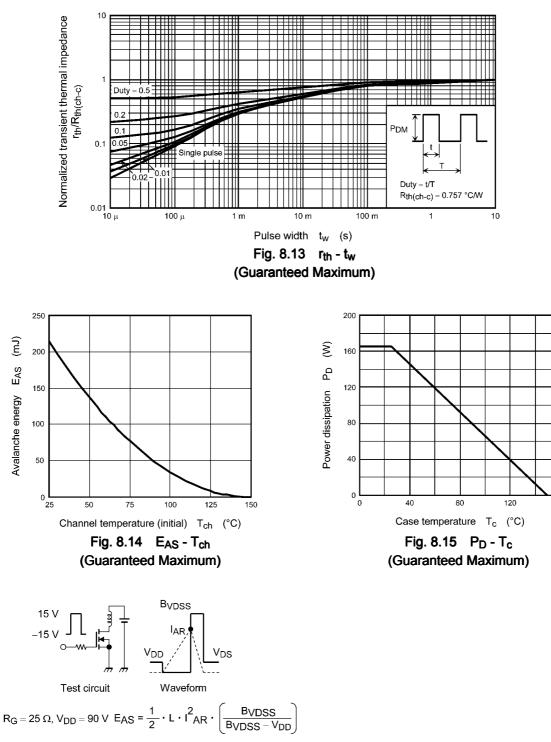
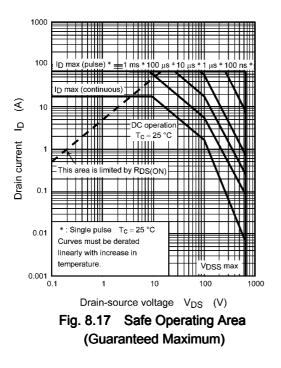


Fig. 8.16 Test Circuit/Waveform

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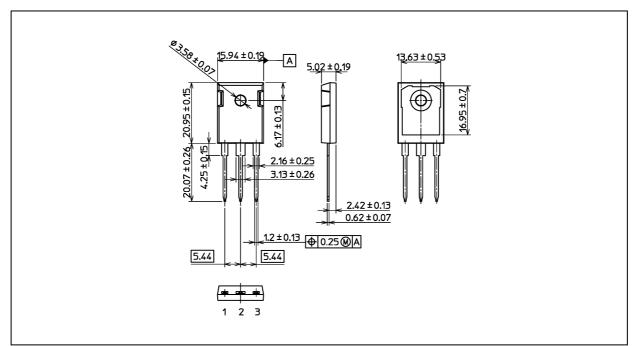


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



### Package Dimensions

Unit: mm



### Weight: 6.15 g (typ.)

	Package Name(s)
JEITA: SC-65	
TOSHIBA: 2-16L1A	
Nickname: TO-247	

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